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NOTICE OF ALLOWANCE AND FEE(S) DUE

22204

7590

02/03/2004

NIXON PEABODY, LLP 401 9TH STREET, NW SUITE 900 WASINGTON, DC 20004-2128 EXAMINER

FLORES RUIZ, DELMA R

ART UNIT

PAPER NUMBER

2828

DATE MAILED: 02/03/2004

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/504,782	02/15/2000	Masahiro Kume	0819-337	8307

TITLE OF INVENTION: SEMICONDUCTOR LASER DEVICE OPTICAL DISK APPARATUS AND OPTICAL INTEGRATED UNIT

APPLN, TYPE	SMALL ENTITY	ISSUE FEE	PUBLICATION FEE	TOTAL FEE(S) DUE	DATE DUE
nonprovisional	NO	\$1330	\$0	\$1330	05/03/2004

THE APPLICATION IDENTIFIED ABOVE HAS BEEN EXAMINED AND IS ALLOWED FOR ISSUANCE AS A PATEN PROSECUTION ON THE MERITS IS CLOSED. THIS NOTICE OF ALLOWANCE IS NOT A GRANT OF PATENT RIGHT THIS APPLICATION IS SUBJECT TO WITHDRAWAL FROM ISSUE AT THE INITIATIVE OF THE OFFICE OR UPO PETITION BY THE APPLICANT. SEE 37 CFR 1.313 AND MPEP 1308.

THE ISSUE FEE AND PUBLICATION FEE (IF REQUIRED) MUST BE PAID WITHIN THREE MONTHS FROM TH MAILING DATE OF THIS NOTICE OR THIS APPLICATION SHALL BE REGARDED AS ABANDONED. THE STATUTORY PERIOD CANNOT BE EXTENDED. SEE 35 U.S.C. 151. THE ISSUE FEE DUE INDICATED ABOV REFLECTS A CREDIT FOR ANY PREVIOUSLY PAID ISSUE FEE APPLIED IN THIS APPLICATION. THE PTOL-85B (O AN EQUIVALENT) MUST BE RETURNED WITHIN THIS PERIOD EVEN IF NO FEE IS DUE OR THE APPLICATION WIL BE REGARDED AS ABANDONED.

HOW TO REPLY TO THIS NOTICE:

I. Review the SMALL ENTITY status shown above.

If the SMALL ENTITY is shown as YES, verify your current SMALL ENTITY status:

A. If the status is the same, pay the TOTAL FEE(S) DUE shown above.

B. If the status is changed, pay the PUBLICATION FEE (if required) and twice the amount of the ISSUE FEE shown above and notify the United States Patent and Trademark Office of the change in status, or

If the SMALL ENTITY is shown as NO:

- A. Pay TOTAL FEE(S) DUE shown above, or
- B. If applicant claimed SMALL ENTITY status before, or is n claiming SMALL ENTITY status, check the box below and enclo the PUBLICATION FEE and 1/2 the ISSUE FEE shown above.
- ☐ Applicant claims SMALL ENTITY status. See 37 CFR 1.27.
- II. PART B FEE(S) TRANSMITTAL should be completed and returned to the United States Patent and Trademark Office (USPTO) w your ISSUE FEE and PUBLICATION FEE (if required). Even if the fee(s) have already been paid, Part B Fee(s) Transmittal should completed and returned. If you are charging the fee(s) to your deposit account, section "4b" of Part B Fee(s) Transmittal should completed and an extra copy of the form should be submitted.
- III. All communications regarding this application must give the application number. Please direct all communications prior to issuance Mail Stop ISSUE FEE unless advised to the contrary.

IMPORTANT REMINDER: Utility patents issuing on applications filed on or after Dec. 12, 1980 may require payment maintenance fees. It is patentee's responsibility to ensure timely payment of maintenance fees when due.

PART B - FEE(S) TRANSMITTAL

Complete and send this form, together with approable fee(s), to: Mail

Mail Stop ISSUE FEE Commissioner for Patents P.O. Box 1450 Alexandria, Virginia 22313-1450

			or <u>Fax</u>	(703) 746-4000		
INSTRUCTIONS: This for appropriate. All further co-indicated unless corrected maintenance fee notification	below or directed otherwise	smitting the ISSU Patent, advance or in Block 1, by (a	E FEE and PUBL ders and notification) specifying a new	ICATION FEE (if requirements of maintenance fees to correspondence address	nired). Blocks 1 through 4 s will be mailed to the current ; and/or (b) indicating a sepa	hould be completed wh correspondence address arate "FEE ADDRESS"
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NIXON PEABO	DY, LLP			Ce	rtificate of Mailing or Trans	smission
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APPLICATION NO.	FILING DATE	_	FIRST NAMED INVI	ENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/504,782	02/15/2000		Masahiro Kun	ne	0819-337	8307
TITLE OF INVENTION: S	EMICONDUCTOR LASER	DEVICE OPTICA	AL DISK APPARA	TUS AND OPTICAL IN	TEGRATED UNIT	
APPLN. TYPE	SMALL ENTITY	ISSUE FI	EE	PUBLICATION FEE	TOTAL FEE(S) DUE	DATE DUE
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FLORES RU	IZ, DELMA R	2828		372-043000	J	
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CFR 1.363).	e address of indication of F	ee Address (37		on the patent front page, o 3 registered patent a		
☐ Change of correspond	ence address (or Change of C	Correspondence	agents OR, alte	matively, (2) the name	of a single	
Address form PTO/SB/1	22) attached.	on opponent		a member a registered		
☐ "Fee Address" indication (or "Fee Address" Indication form PTO/SB/47; Rev 03-02 or more recent) attached. Use of a Consumber is required.			agent) and the names of up to 2 registered patent attorneys or agents. If no name is listed, no name will be printed.			
3. ASSIGNEE NAME AND	RESIDENCE DATA TO B	E PRINTED ON T	THE PATENT (prin	t or type)		
			\ <u>*</u>	* 1 '	ssignee data is only appropri	ate when an assignment
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(A) NAME OF ASSIGN	EE	(B	B) RESIDENCE: (C	ITY and STATE OR CO	UNTRY)	
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Please check the appropriate	e assignee category or catego	ries (will not be pr	inted on the patent);	individual 🗆	corporation or other private gr	roup entity 🔾 governm
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☐ Issue Fee			☐ A check in the amount of the fee(s) is enclosed.			
☐ Publication Fee			☐ Payment by credit card. Form PTO-2038 is attached.			
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Director for Patents is reque	sted to apply the Issue Fee a	nd Publication Fee			ssue fee to the application ide	
(Authorized Signature)		(Date)		<u> </u>		
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NOTE; The Issue Fee an other than the applicant; interest as shown by the re	d Publication Fee (if require a registered attorney or ag cords of the United States Pa	ed) will not be accent; or the assigned	cepted from anyone ee or other party in	e n		
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This collection of information is required by 37 CFR 1.311. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 12 minutes to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S. Department of Commerce, Alexandria, Virginia 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, Alexandria, Virginia 22313-1450.

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APPLICATION NO.	FILI	NG DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO		
09/504,782	02	/15/2000	Masahiro Kume	0819-337	8307		
22204	7590	02/03/2004		EXAM	EXAMINER		
NIXON PEABODY, LLP 401 9TH STREET, NW			FLORES RUIZ, DELMA R				
SUITE 900	EI, NW			ART UNIT	PAPER NUMBER		
WASINGTON,	ASINGTON, DC 20004-2128			2828	=		
				DATE MAILED: 02/03/2004	4		

Determination of Patent Term Extension under 35 U.S.C. 154 (b)

(application filed after June 7, 1995 but prior to May 29, 2000)

The Patent Term Extension is 0 day(s). Any patent to issue from the above-identified application will include indication of the 0 day extension on the front page.

If a Continued Prosecution Application (CPA) was filed in the above-identified application, the filing date th determines Patent Term Extension is the filing date of the most recent CPA.

Applicant will be able to obtain more detailed information by accessing the Patent Application Information Retriev (PAIR) system (http://pair.uspto.gov).

Any questions regarding the Patent Term Extension or Adjustment determination should be directed to the Office Patent Legal Administration at (703) 305-1383. Questions relating to issue and publication fee payments should directed to the Customer Service Center of the Office of Patent Publication at (703) 305-8283.

	Application No.	Applicant(s)	
	09/504,782	KUME ET AL.	
Notice of Allowability	Examiner	Art Unit	
	Dalma D. Flares Duin	2020	
	Delma R. Flores Ruiz	2828	
The MAILING DATE of this communication appeal All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RI	(OR REMAINS) CLOSED in the or other appropriate communities. This application is sub-	nis application. If not included cation will be mailed in due course.	
1. This communication is responsive to 10-31/2003.			
2. The allowed claim(s) is/are 1-6.			
3. A The drawings filed on 15 February 2000 are accepted by the	he Examiner.		
 Acknowledgment is made of a claim for foreign priority ur a)	nder 35 U.S.C. § 119(a)-(d) or	(f) .	
 Certified copies of the priority documents have 	e been received.		
Certified copies of the priority documents have	been received in Application	No	
3. Copies of the certified copies of the priority do	cuments have been received in	n this national stage application from	the
International Bureau (PCT Rule 17.2(a)).			
* Certified copies not received:			
 Acknowledgment is made of a claim for domestic priority up reference was included in the first sentence of the specifical 			fic
(a) The translation of the foreign language provisional a	,		
 Acknowledgment is made of a claim for domestic priority up in the first sentence of the specification or in an Application 		121 since a specific reference was in	nciuded
Applicant has THREE MONTHS FROM THE "MAILING DATE" of below. Failure to timely comply will result in ABANDONMENT of			
7. A SUBSTITUTE OATH OR DECLARATION must be subm INFORMAL PATENT APPLICATION (PTO-152) which give			OF .
 CORRECTED DRAWINGS (as "replacement sheets") mus (a) including changes required by the Notice of Draftspers hereto or 2) to Paper No 		PTO-948) attached	
(b) \square including changes required by the proposed drawing c	correction filed, which h	nas been approved by the Examiner.	
(c) including changes required by the attached Examiner's	s Amendment / Comment or in	the Office action of Paper No.	
Identifying indicia such as the application number (see 37 CFR 1 each sheet. Replacement sheet(s) should be labeled as such in t			
 DEPOSIT OF and/or INFORMATION about the depo- attached Examiner's comment regarding REQUIREMENT FOR T 			
Attachment(s)			
1☐ Notice of References Cited (PTO-892)	5☐ Notice of Inform	nal Patent Application (PTO-152)	
2☐ Notice of Draftperson's Patent Drawing Review (PTO-948)	6☐ Interview Sumr	nary (PTO-413), Paper No	
3⊠ Information Disclosure Statements (PTO-1449 or PTO/SB/08 Paper No. 8,9,12,16,4 / €	3), 7⊠ Examiner's Am	endment/Comment	
4☐ Examiner's Comment Regarding Requirement for Deposit	8⊠ Examiner's Sta	tement of Reasons for Allowance	
of Biological Material	9 <u>□</u> Other .	Panepal IP	
•	SUF	ERVISORY PATENT EXAMINER ECHNOLOGY CENTER 2800	

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DETAILED ACTION

EXAMINER'S AMENDMENT

An examiner's amendment to the record appears below. Should the changes and/or additions be unacceptable to applicant, an amendment may be filed as provided by 37 CFR 1.312. To ensure consideration of such an amendment, it MUST be submitted no later than the payment of the issue fee.

Authorization for this examiner's amendment was given in a telephone interview with Jerome Massie on 1/20/2004.

In claim 1, A semiconductor laser device comprising; a first cladding layer, which is made of a nitride semiconductor of a first conductivity type and is formed over substrate; an active layer, which is made of In_yGa_{1-y}N and is formed over the first cladding layer; a second cladding layer, which is made of still another nitride semiconductor of a second conductivity type and is formed over the active; and an spontaneous-emission-absorbing layer, which is made of still another nitride semiconductor of the first conductivity type and has and energy gap as absorbing-spontaneous emission layer, for emission from the active layer, is formed between the substrate and the first cladding layer, an In_xGa_{1-x}N of the first conductivity type is formed

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between the substrate and the first cladding layer, wherein 0 < x < 1, 0 < y < 1 and x > y in the composition of In.

In claim 4, A semiconductor laser device comprising; a first cladding layer, which is made of a nitride semiconductor of a first conductivity type and is formed over substrate; an active layer, which is made of $In_yGa_{1-y}N$ and is formed over the first cladding layer; a second cladding layer, which is made of still another nitride semiconductor of a second conductivity type and is formed over the active; an electrode formed over the second cladding layer, and an spontaneous-emission-absorbing layer, which is made of still another nitride semiconductor of the first conductivity type and has and energy gap as absorbing-spontaneous emission layer, for emission from the active layer, is formed between the substrate and the first cladding layer, an $In_xGa_{1-x}N$ of the first conductivity type is formed between the second cladding layer and electrode, wherein 0 < x < 1, 0 < y < 1 and x > y in the composition of In.

Cancel claims 7 - 30.

Allowable Subject Matter

The following is an examiner's statement of reasons for allowance: claim 1 has been allowed over the prior art because they fail to teach a semiconductor laser device

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comprising; a first cladding layer, which is made of a nitride semiconductor of a first conductivity type and is formed over substrate; an active layer, which is made of $In_yGa_{1-y}N$ and is formed over the first cladding layer; a second cladding layer, which is made of still another nitride semiconductor of a second conductivity type and is formed over the active; and an spontaneous-emission-absorbing layer, which is made of still another nitride semiconductor of the first conductivity type and has and energy gap as absorbing-spontaneous emission layer, for emission from the active layer, is formed between the substrate and the first cladding layer, an $In_xGa_{1-x}N$ of the first conductivity type is formed between the substrate and the first cladding layer, wherein 0 < x < 1, 0 < y < 1 and x > y in the composition of In.

Claim 2 – 3 has been found allowable due to their dependency on claim 1.

The following is an examiner's statement of reasons for allowance: claim 4 has been allowed over the prior art because they fail to teach a semiconductor laser device comprising; a first cladding layer, which is made of a nitride semiconductor of a first conductivity type and is formed over substrate; an active layer, which is made of In_yGa₁. yN and is formed over the first cladding layer; a second cladding layer, which is made of still another nitride semiconductor of a second conductivity type and is formed over the

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active; an electrode formed over the second cladding layer, and <u>an spontaneous</u><u>emission-absorbing layer, which is made of still another nitride semiconductor of</u>
<u>the first conductivity type and has and energy gap as absorbing-spontaneous</u>
<u>emission layer, for emission from the active layer, is formed between the</u>
<u>substrate and the first cladding layer, an $ln_xGa_{1-x}N$ of the first conductivity type is</u>
<u>formed between the second cladding layer and electrode, wherein 0 < x < 1, 0 < y < 1 and x > y in the composition of ln.</u>

Claims 5 – 6 has been found allowable due to their dependency on claim 4.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reason for Allowance".

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Delma R. Flores Ruiz whose telephone number is (571) 272-1940. The examiner can normally be reached on M - F.

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If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Paul Ip can be reached on (571) -272-1941. The fax phone number for the organization where this application or proceeding is assigned is (703) 872-9306.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 306-3431.

Delma R. Flores Ruiz

Examiner Art Unit 2828

DRFR/PI January 22, 2004 Paul Ip

Supervisor Patent Examiner Art Unit 2828